

	Typ	L #	Hits	S arch Text	DBs
1	BRS	L1	17185	(implantation or implant or implanting or adjust or adjusting or dope or doping) near10 threshold	USPAT; US-PG PUB
2	BRS	L2	630	1 same (low adj2 voltage)	USPAT; US-PG PUB
3	BRS	L3	321	1 near20 (low adj2 voltage)	USPAT; US-PG PUB
4	BRS	L4	29374	(source or drain) near10 (high adj2 voltage)	USPAT; US-PG PUB
5	BRS	L5	15	4 same 3	USPAT; US-PG PUB
6	IS&R	L6	1	("6555456").PN.	USPAT; US-PG PUB
7	BRS	L7	3341	(barrier adj2 (layer or film)) near5 ("ta" or tantalum or "taN" or (tantalum adj2 nitride))	USPAT; US-PG PUB
8	BRS	L8	154321	"3" near15 (substrate)	USPAT; US-PG PUB
9	BRS	L9	426	((barrier adj2 (layer or film)) near5 ("ta" or tantalum or "taN" or (tantalum adj2 nitride))) near15 (substrate)	USPAT; US-PG PUB
10	BRS	L10	129	(metal or electrode) near20 (((barrier adj2 (layer or film)) near5 ("ta" or tantalum or "taN" or (tantalum adj2 nitride)))) near15 (substrate))	USPAT; US-PG PUB
11	BRS	L11	2471	ferroelectric adj2 capacitor	USPAT; US-PG PUB
12	CUST	L12	272484	"257"	USPAT; US-PG PUB
13	BRS	L13	1480	(ferroelectric adj2 capacitor) and "257"	USPAT; US-PG PUB
14	BRS	L14	2497	438/257	USPAT; US-PG PUB
15	BRS	L15	6734	thin adj2 gate adj2 (oxide or dielectric or insulator or insulating)	USPAT; US-PG PUB
16	BRS	L16	2067	thick adj2 gate adj2 (oxide or dielectric or insulator or insulating)	USPAT; US-PG PUB
17	BRS	L17	640	(thin adj2 gate adj2 (oxide or dielectric or insulator or insulating)) same (thick adj2 gate adj2 (oxide or dielectric or insulator or insulating))	USPAT; US-PG PUB
18	BRS	L18	94	((thin adj2 gate adj2 (oxide or dielectric or insulator or insulating)) same (thick adj2 gate adj2 (oxide or dielectric or insulator or insulating))) same (threshold)	USPAT; US-PG PUB

	Typ	L #	Hits	Search Text	DBs
19	BRS	L19	978	(different or variable or varied) adj3 gate adj3 (oxide or dielectric or insulating or insulator)	USPAT; US-PG PUB
20	BRS	L20	3	((thin adj2 gate adj2 (oxide or dielectric or insulator or insulating)) same (thick adj2 gate adj2 (oxide or dielectric or insulator or insulating))) same (threshold)) same ((different or variable or varied) adj3 gate adj3 (oxide or dielectric or insulating or insulator))	USPAT; US-PG PUB
21	BRS	L21	442	((thin adj2 gate adj2 (oxide or dielectric or insulator or insulating)) same (thick adj2 gate adj2 (oxide or dielectric or insulator or insulating))) and (threshold)	USPAT; US-PG PUB
22	BRS	L22	12926	(implantation or implant or implanting or adjust or adjusting) near5 threshold	USPAT; US-PG PUB
23	BRS	L23	202	(low adj2 voltage) near25 ((implantation or implant or implanting or adjust or adjusting) near5 threshold)	USPAT; US-PG PUB
24	BRS	L24	13	((low adj2 voltage) near25 ((implantation or implant or implanting or adjust or adjusting) near5 threshold)) near25 (source or drain)	USPAT; US-PG PUB
25	BRS	L25	47	((low adj2 voltage) near25 ((implantation or implant or implanting or adjust or adjusting) near5 threshold)) same (source or drain)	USPAT; US-PG PUB
26	BRS	L26	34	((low adj2 voltage) near25 ((implantation or implant or implanting or adjust or adjusting) near5 threshold)) same (source or drain)) not (((low adj2 voltage) near25 ((implantation or implant or implanting or adjust or adjusting) near5 threshold)) near25 (source or drain))	USPAT; US-PG PUB